# SF51 THRU SF57



## 5.0 AMP SUPER FAST RECTIFIERS



## **FEATURES**

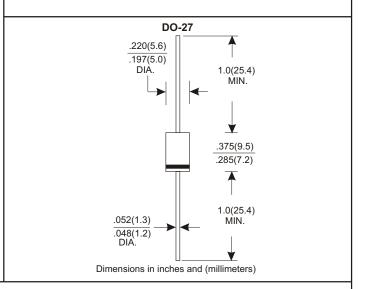
- \* Low forward voltage drop
- \* High current capability
- \* High reliability
- \* High surge current capability
- \* Good for switching mode application

### **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any

## VOLTAGE RANGE 50 to 600 Volts CURRENT

5.0 Amperes



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	SF51	SF52	SF53	SF54	SF55	SF56	SF57	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V
Maximum RMS Voltage	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current								
.375"(9.5mm) Lead Length at Ta=55°C	5.0							Α
Peak Forward Surge Current, 8.3 ms single half sine-wave								
superimposed on rated load (JEDEC method)	150						Α	
Maximum Instantaneous Forward Voltage at 5.0A		0.95 1.3				1.7	V	
Maximum DC Reverse Current Ta=25°C		5.0						μΑ
at Rated DC Blocking Voltage Ta=100°C		100						
Maximum Reverse Recovery Time (Note 1)		35						nS
Typical Junction Capacitance (Note 2)		90						pF
Operating and Storage Temperature Range TJ, TsTG	-65—+150							°C

#### NOTES:

- 1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

#### RATING AND CHARACTERISTIC CURVES (SF51 THRU SF57) FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC FIG.2-TYPICAL FORWARD CURRENT **DERATING CURVE** 10 NONINDUCTIVE NONINDUCTIVE +0.5A AVERAGE FORWARD CURRENT,(A) 6 5 (+) 0 Z D.U.T. 25Vdc PULSE GENERATO (NOTE 2) (approx.) -0.25A Single Phase (-) 3 Half Wave 60Hz Resistive Or Inductive Load INDUCTIVE 2 0.375"(9.5mm) Lead Length -1.0A NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF → 1cm -0 2. Rise Time= 10ns max., Source Impedance= 50 ohms. SET TIME BASE FOR 0 25 50 100 125 150 175 50 / 10ns / cm AMBIENT TEMPERATURE,(°C) FIG.3-TYPICAL FORWARD FIG.4-TYPICAL REVERSE **CHARACTERISTICS CHARACTERISTICS** 50 50 INSTANTANEOUS FORWARD CURRENT, (A) Tj=100°C 10 10 REVERSE LEAKAGE CURRENT, (µA) 3.0 3.0 1.0 1.0 Tj=25°C -Pulse Width 300us 1% Duty Cycle Tj=25°C 0.1 0.1 .01 .01 .4 .6 .8 1.0 1.2 1.6 1.8 0 40 60 80 100 120 140 FORWARD VOLTAGE,(V) PERCENT OF RATED PEAK REVERSE VOLTAGE,(%) FIG.6-TYPICAL JUNCTION CAPACITANCE FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT 350 150 PEAK FORWARD SURGE CURRENT,(A) 300 JUNCTION CAPACITANCE, (pF) 120 250 200 90 8.3ms Single Half Tj=25°C 150 Sine Wave 60 JEDEC method 100 30 50

100

50

1

5

10

NUMBER OF CYCLES AT 60Hz

.01

.05

.1

REVERSE VOLTAGE,(V)

10

100

50

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